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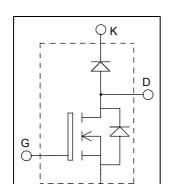




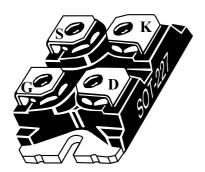




ISOTOP® Boost chopper MOSFET Power Module



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$$\begin{split} V_{DSS} &= 500 V \\ R_{DSon} &= 65 m \Omega \ Max \ @ \ Tj = 25^{\circ} C \\ I_D &= 58 A \ @ \ Tc = 25^{\circ} C \end{split}$$

Application

- AC and DC motor control
- Switched Mode Power Supplies
- Power Factor Correction
- Brake switch

Features

- Power MOS 8TM MOSFETs
 - Low R_{DSon}
 - Low input and Miller capacitance
 - Low gate charge
 - Avalanche energy rated
 - Very rugged
- ISOTOP® Package (SOT-227)
- Very low stray inductance
- High level of integration

Benefits

- Outstanding performance at high frequency operation
- Stable temperature behavior
- Very rugged
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Easy paralleling due to positive TC of VCEsat
- RoHS Compliant

Absolute maximum ratings

Symbol	Parameter		Max ratings	Unit
$V_{ m DSS}$	Drain - Source Breakdown Voltage		500	V
Ţ	Continuous Drain Current	$T_c = 25^{\circ}C$	58	
I_D	Continuous Diani Current	$T_c = 80^{\circ}C$	43	A
I_{DM}	Pulsed Drain current		270	
V_{GS}	Gate - Source Voltage		±30	V
R_{DSon}	Drain - Source ON Resistance		65	mΩ
P_{D}	Maximum Power Dissipation	$T_c = 25^{\circ}C$	543	W
I_{AR}	Avalanche current (repetitive and non repetitive)		42	A

📆 CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handing Procedures Should Be Followed.



All ratings @ $T_j = 25$ °C unless otherwise specified

Electrical Characteristics

Symbol	Characteristic	Test Conditions		Min	Typ	Max	Unit
I_{DSS}	Zero Gate Voltage Drain Current	$V_{\rm DS} = 500 \rm V$	$T_j = 25$ °C			250	^
		$V_{GS} = 0V$	$T_j = 125$ °C			1000	μΑ
R _{DS(on)}	Drain – Source on Resistance	$V_{GS} = 10V, I_D = 42A$				65	mΩ
V _{GS(th)}	Gate Threshold Voltage	$V_{GS} = V_{DS}$, $I_D = 2.5 \text{mA}$		3	4	5	V
I_{GSS}	Gate – Source Leakage Current	$V_{GS} = \pm 30 \text{ V}$	•			±100	nA

Dynamic Characteristics

Symbol	Characteristic	Test Conditions	Min	Typ	Max	Unit
C_{iss}	Input Capacitance	$V_{GS} = 0V$		10800		
C_{oss}	Output Capacitance	$V_{DS} = 25V$		1164		pF
C_{rss}	Reverse Transfer Capacitance	f = 1MHz		148		
Q_{g}	Total gate Charge	$V_{GS} = 10V$		340		
Q_{gs}	Gate – Source Charge	$V_{Bus} = 250V$		75		nC
Q_{gd}	Gate – Drain Charge	$I_D = 42A$		155		
$T_{d(on)}$	Turn-on Delay Time	Resistive switching @ 25°C		60		
$T_{\rm r}$	Rise Time	$V_{GS} = 15V$ $V_{Bus} = 333V$ $I_D = 42A$		70		ng
$T_{d(off)}$	Turn-off Delay Time			155		ns
T_{f}	Fall Time	$R_G = 2.2\Omega$		50		

Chopper diode ratings and characteristics

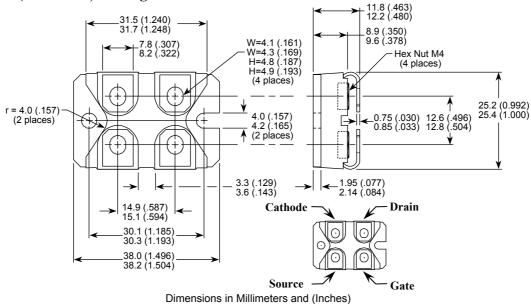
Symbol	Characteristic	Test Conditions		Min	Тур	Max	Unit
V_{RRM}	Maximum Peak Repetitive Reverse Voltage			600			V
I_{RM}	Maximum Reverse Leakage Current	V _R =600V	$T_i = 25^{\circ}C$ $T_i = 125^{\circ}C$			25 500	μΑ
I_{F}	DC Forward Current		$Tc = 90^{\circ}C$		30		A
		$I_F = 30A$			1.8	2.2	
V_{F}	Diode Forward Voltage	$I_F = 60A$			2.2		V
		$I_F = 30A$	$T_i = 125$ °C		1.5		
+	Reverse Recovery Time	I - 20A	$T_j = 25$ °C		25		ns
t_{rr}	Reverse Recovery Time		$T_j = 125$ °C		160		115
Q _{rr}	Reverse Recovery Charge	$di/dt = 200 A/\mu s$	$T_j = 25$ °C		35		пC
		·	$T_{j} = 125^{\circ}C$		480		пС

Thermal and package characteristics

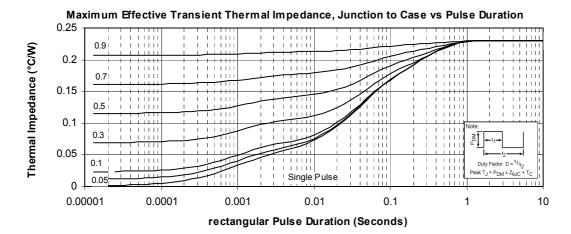
Characteristic		Min	Тур	Max	Unit
Junction to Case Thermal Resistance	Mosfet			0.23	°C/W
	Diode			1.05	
Junction to Ambient (IGBT & Diode)				20	
RMS Isolation Voltage, any terminal to case t = 1 min, 50/60Hz		2500			V
Storage Temperature Range		-40		150	°C
Max Lead Temp for Soldering:0.063" from case for 10 sec				300	C
Mounting torque (Mounting = 8-32 or 4mm Machine and terminals = 4mm Machine)				1.5	N.m
Package Weight			29.2		g
	Junction to Case Thermal Resistance Junction to Ambient (IGBT & Diode) RMS Isolation Voltage, any terminal to case t = 1 min, 50/60Hz Storage Temperature Range Max Lead Temp for Soldering:0.063" from case for 10 sec Mounting torque (Mounting = 8-32 or 4mm Machine and terminals = 4	Junction to Case Thermal Resistance Mosfet Diode Junction to Ambient (IGBT & Diode) RMS Isolation Voltage, any terminal to case t = 1 min, 50/60Hz Storage Temperature Range Max Lead Temp for Soldering:0.063" from case for 10 sec Mounting torque (Mounting = 8-32 or 4mm Machine and terminals = 4mm Machine)	Junction to Case Thermal Resistance Mosfet	Junction to Case Thermal Resistance Mosfet Diode Junction to Ambient (IGBT & Diode) RMS Isolation Voltage, any terminal to case t = 1 min, 50/60Hz Storage Temperature Range -40 Max Lead Temp for Soldering: 0.063" from case for 10 sec Mounting torque (Mounting = 8-32 or 4mm Machine and terminals = 4mm Machine)	Junction to Case Thermal Resistance Mosfet 0.23 Junction to Ambient (IGBT & Diode) 20 RMS Isolation Voltage, any terminal to case t = 1 min, 50/60Hz 2500 Storage Temperature Range -40 150 Max Lead Temp for Soldering:0.063" from case for 10 sec 300 Mounting torque (Mounting = 8-32 or 4mm Machine and terminals = 4mm Machine) 1.5



SOT-227 (ISOTOP®) Package Outline



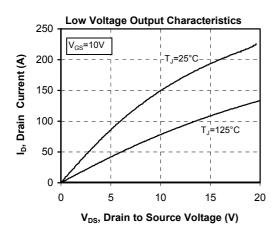
Typical Mosfet Performance Curve

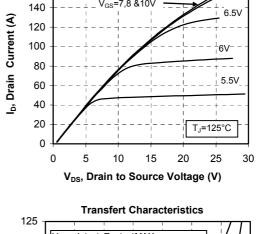


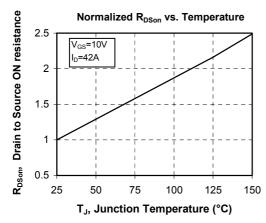


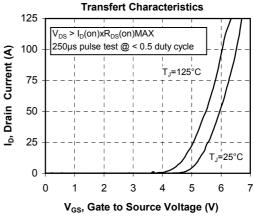
Low Voltage Output Characteristics

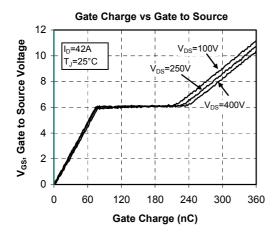
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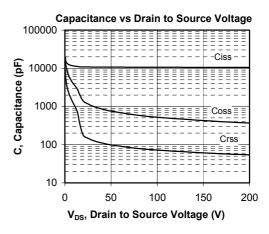






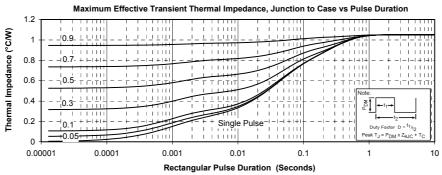


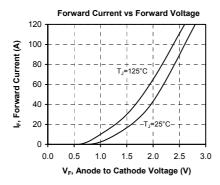


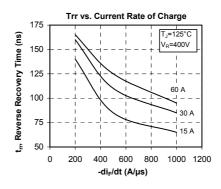


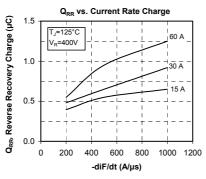


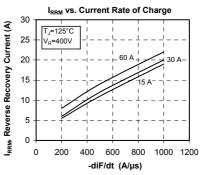
Typical Diode Performance Curve

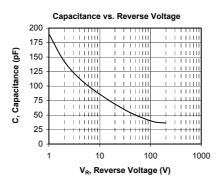


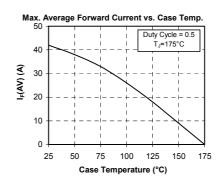












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